

Phase Shifter-less Wide Band FM IF Demodulator IC for Voice

■ FEATURES

- Unnecessary External phase shifter (CD or IFT)
- Auto IF detection
 - IF = 1.5MHz to 15MHz
 - * S-curve characteristic cannot be obtained
- Demodulated Output Frequency Range
 - fmod = 20Hz to 100kHz
 - * External parts modification : up to 300kHz
- Excellent electrical characteristics

SNR	80dB	@fdev = 75kHz
THD	0.015%	@fdev = 75kHz

APPLICATION

- Wireless microphone (RF/IR)
- Wireless headphone (RF/IR)
- Intercom , Door phone

■ GENERAL DESCRIPTION

NJW2311 is the IC which has the automatic IF detection of FM modulating signal of the 1.5MHz to 15MHz, that operates from 4.5V, and makes unnecessary such as the phase-shifter which was conventionally required as external parts.

An IF amplifier, a FM demodulator and a low noise Op-amplifier are built in.

Since high S/N ratio and low distortion characteristics are realized, it is the best for the various FM Receivers of wireless or wired Voice communications.

FM Demodulation characteristic



BLOCK DIAGRAM





■ PIN CONFIGURATION



PIN NO.	SYMBOL	DESCRIPTION
1	GND1	GND
2	IF IN	IF input
3	IF DEC	IF decoupling
4	FIL1	Vref decoupling
5	GND2	GND
6	V*2	Power supply
7	FIL2	Demodulation noise removal
8	CS	Current output
9	V*1	Power supply
10	FIL3	Demodulation filter
11	DEM OUT	Demodulated signal output
12	OP⁺IN	Op-amp non-inverting (+) input
13	OP⁻IN	Op-amp inverting (-) input
14	OP OUT	Op-amp output

MARK INFORMATION



ORDERING INFORMATION

PART NUMBER	PACKAGE OUTLINE	RoHS	HALOGEN- FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	MOQ(pcs)
NJW2311V	SSOP14	>	~	Sn2Bi	2311	65	2,000

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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺ 1,V ⁺ 2	5.5	V
Power Dissipation (Ta=25°C)	PD	440	mW
Operating Temperature Range	T _{opr}	-40 to +85	°C
Storage Temperature Range	T _{stg}	-50 to +125	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V*1,V*2	+4.5 to +5.5	V
IF operating frequency	f _{IF}	1.5 to 15	MHz

■ ELECTRICAL CHARACTERISTICS

(Ta = 25 °C, $V^+1 = V^+2 = 5V$, IF IN = 10.7MHz / 100dBuV, fdev = ±75kHz, fmod = 1kHz, unless otherwise noted)

PARAMETER*	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Consumption	I _{CC}		-	23	28	mA
IF Input Resistance	R _{IIF}	between Pin2 and 3	15	20	25	kΩ
Output DC Level	V _{DC}		2.0	2.5	3.0	V
Output AF Level	V _{AF}		190	250	310	mVrms
Signal to Noise Ratio	S/N	A-weight	74	80	-	dB
Total Harmonics Distortion	THD1	$LPF = 20kHz$, fdev = $\pm 75kHz$	-	0.015	-	0/
	THD2	$LPF = 20kHz$, fdev = $\pm 200kHz$	-	0.03	-	%
Receiver Sensitivity	Sen	A-weight	-	55	-	dBuV
AM Rejection Ratio	AMR	LPF = 20kHz , AM = 30%	-	55	-	
Output AF frequency characteristics	f _{DET} 1	fmod = 100kHz , relative attenuation from fmod=1kHz condition	-	-2	-]
	f _{DET} 2	fmod = 20Hz , relative attenuation from fmod=1kHz condition	-	-3.5	-	dB
OP OUT Load Capability	R _{OD}	$Ro = 4.7k\Omega$, relative attenuation from no-load condition	-	0	3	

* Refer to GLOSSARY (page 6) about the contents of PARAMETER.

■ MEASURING CIRCUIT



■ TYPICAL CHARACTERISTICS

(Ta = 25 °C, V⁺1 = V⁺2 = 5V, IF IN = 10.7MHz / 100dBuV, fdev = ±75kHz, fmod = 1kHz, unless otherwise noted)



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 $(Ta = 25 \degree C, V^{+}1 = V^{+}2 = 5V, IF IN = 10.7MHz / 100dBuV, fdev = \pm 75kHz, fmod = 1kHz, unless otherwise noted)$

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■ GLOSSARY

SYMBOL	PARAMETER	TERMINAL	DESCRIPTION
I _{CC}	Current Consumption	V ⁺ 1,V ⁺ 2	Total current through V ⁺ 1(Pin9) and V ⁺ 2(Pin6) at no signal condition.
R _{I⊮}	IF Amplifier Input Impedance	IF IN, IF DET	Impedance between IF IN (Pin2) and IF DEC (Pin3).
V _{DC}	Output DC Level	OP OUT	DC output voltage at OP OUT terminal (Pin14) under IF IN=10.7MHz carrier signal input condition.
V _{AF}	Output AF Level	OP OUT	AC output voltage at OP OUT terminal (Pin14) under a demodulated signal input condition.
S/N	Signal to Noise Ratio	OP OUT	Signal-to-Noise ratio of demodulated signal. $S / N = 20 \log \frac{Signal}{Noise}$ Signal: AC output voltage (V _{AF}) of the OP OUT terminal (Pin14) at standard condition Noise: AC output voltage (V _{AF}) of the OP OUT terminal (Pin14) at non-modulated condition
THD	Total Harmonic Distortion	OP OUT	THD is the factor which shows the degree of the distortion of the FM demodulated output signal and is the ratio of the total harmonics versus the fundamental wave. $THD = \frac{\sqrt{V2^2 + V3^2 + \cdots + V10^2}}{V1}$ V1: effective voltage of fundamental frequency. V2, V3 ··· V10: effective voltage of harmonic frequency. THD1: fdev = ±75kHz condition THD2: fdev = ±200kHz condition
Sen	Demodulation Sensitivity	OP OUT	The minimum input signal point which a demodulated output signal is more than 50dB of S/N which isn't buried in noise.
AMR	AM Rejection Ratio	OP OUT	Ratio of AM demodulated signal level and FM demodulated signal level. $\begin{array}{l} AMR = 20 \log \frac{V_{AF}}{AM \ demodulated \ level} \\ V_{AF} : \mbox{Output AF Level} \\ AM \ demodulated \ level: \ 100 dB\mu, \ AM = 30\% \ mod, \ fmod = 1 \ kHz \end{array}$
f _{DET}	Output AF Frequency Characteristics	OP OUT	Flatness of FM demodulated output signal level over wide modulation frequency range. f_{DET} 1: fmod = 100kHz, relative attenuation from fmod = 1kHz condition f_{DET} 2: fmod = 20Hz, relative attenuation from fmod = 1kHz condition
R _{OD}	OP OUT Load Capability	OP OUT	Attenuation of the FM demodulated signal level by connection of the load resistance. $Ro = 4.7k\Omega$, relative attenuation from no-load condition
IF	Intermediate Frequency		Down-converted frequency in the intermediate receiver section.
fmod	IF Signal Modulation		Frequency of base-band signal to generate FM IF signal.
fdev	IF signal deviation		FM deviation of an IF signal.

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APPLICATION NOTE

> Influence of power supply noise on S/N characteristics

The noise level of the FM demodulated output signal of the NJW2311 may increase when operating without a low noise DC power supply. Actually, when noises are on the power supply terminal (V⁺1, V⁺2), S/N ratio of NJW2311 deteriorates. It's effective to reduce the noise level which appears in the power supply terminal (V⁺1, V⁺2) to get excellent S/N characteristics.

The following is an example to connect a capacitor and a resistor into between an external power supply and the power supply terminal (V^+1 , V^+2) and make it a low pass filter. In this case, the cutoff frequency of the LPF should be set to much lower frequency than the demodulation (AF) frequency.

$$fc = \frac{1}{2\pi\tau}$$
* fc: Cut off frequency
t: Time constant (RC)

On the other hand, a big value of capacitor of the LPF has slow response when the DC power becomes turned on. And, a big value of resistor of the LPF has the drop voltage of the DC power. Therefore please pay attention so that the voltage of the power supply terminal of NJW2311 (V^+1 , V^+2) may fit into a range of the recommended operating condition.

> Reference circuit diagram to prevent degradation of S/N



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> Recommended combination of ICs to boost the receiver sensitivity up

A pre-amplifier before NJW2311 is useful to boost the demodulation sensitivity up. The following of circuit diagram and its characteristics are the recommended combination with NJM2549 to boost the receiver sensitivity up. NJM2549 has a built-in RSSI function, it can use for a carrier squelch.





EVALUATION BOARD



Evaluation board



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PCB layout information

The demodulation sensitivity and electromagnetic interference (EMI) of the NJW 2311 are affected by the pattern layout. Particular attention is required to the pattern layout of the power supply line, GND line, and signal line.

Demodulation sensitivity

If the GND terminal is unstable, or if the grounding points of external components are not preferred location, the reception sensitivity will be reduced. For this reason, please make pattern layout so that parasitic impedance of power supply and GND line is as low as possible.

When it becomes difficult to lower the parasitic impedance, please consider the pattern layout with reference to the following contents.

Improvement of GND stability

Through hole: Reduce the impedance of board GND by increasing the number of through holes with GND of another PCB layer.

Solid pattern: Place the signal line so that it does not cross the GND pattern on the NJW 2311 mounted side.

Pin 7 and 8: Connect to the GND of the surface layer without going through a through hole.

Pin 4: Connect to the GND of the surface layer without going through a through hole.

- GND separation
- Pin 2 and 3: Common GND of the front stage circuit of the IF input

· Enhanced power supply stability

Place the GND of the bypass capacitor of power supply terminal V^+1 (Pin 9) near the GND1 (Pin 1). Place the GND of the bypass capacitor of power supply terminal V^+2 (Pin 6) near the GND2 (Pin 5).

Electro Magnetic Interference (EMI)

The NJW 2311 amplifies the IF input signal to generate a saturation waveform (rectangular wave), and then performs signal processing in the FM demodulator circuit.

When an IF signal is input to these circuits, the circuit current including the input signal frequency and harmonic components flows and noise is generated in a wide frequency range. If this noise component current to the power supply, GND and signal line, electromagnetic interference is radiated using the pattern layout as an antenna. Therefore, please shorten the pattern layout of power supply, GND, and signal line as much as possible.

The equivalent circuit is shown below for the pattern layout when the signal path connected from the filter (input / output impedance: 1 k Ω) to the IF IN terminal (pin 2) is lengthened. When the wire is made longer, the transfer characteristic from the IF IN terminal (pin 2) to TP becomes the blue line on the graph and a peak occurs at a specific frequency. As a countermeasure, by setting a resistor in the immediate vicinity of

the IF IN terminal (pin 2), the transfer characteristic from the IF IN terminal (pin 2) to TP becomes the red line on the graph and the frequency peak can be suppressed.

However, depending on the impedance of the signal path and the resistance value, reception sensitivity may decrease, so be careful.





IF IN - TP Transfer characteristics

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Function Description

The NJW2311 is composed of the IF amplifier, the FM demodulator and the low noise Op-amplifier. The following is the description of the function and terminals of each circuit.

• 2 systems of power supply terminal (V⁺1, V⁺2) and GND terminal (GND1,GND2)

Power supply terminal V⁺1 and GND1 are being used for the comparator circuit which is placed after the IF amplifier circuit. Power supply terminal V⁺2 and GND2 are being used for all circuits except for the above-mentioned comparator part. A reason of separation of power supply is to avoid the harmonic frequencies in IF which occurs at the above-mentioned comparator part.

• IF amplifier circuit (IF AMP)

An IF amplifier circuit is a saturation amplifier to make a clipped signal (square wave) to remove an amplitude noise in an IF signal. The output of the IF amplifier which is the fixed level is sent to the FM demodulator circuit. (Since a FM modulating signal has information in frequency shifting, even if a clipped FM modulating signal doesn't influence information.)

A weak FM signal can be demodulated even in a noisy environment by this way. NJW2311 doesn't have an output terminal of an IF amplifier circuit.

Circuit composition

The IF amplifier circuit consists of a differential amplifier and a comparator, and has a high gain.

• IF IN terminal (Pin2) input impedance is $10k\Omega$, Resistance between Pin2 and 3 is $20k\Omega$ (typical)

An internal resistance of $20k\Omega$ is connected between the IF IN terminal and the IF decoupling terminal. The midpoint of this $20k\Omega$ is connected to the power source for DC biassing through 3 stage of diodes.

Therefore input detector of IF IN terminal will be $10k\Omega$.

• IF IN terminal (Pin2): A CF (ceramic filter) connection example

When connecting CF to the IF IN terminal, it's necessary to consider the impedance-matching between the characteristic impedance (Z) of CF and the IF IN terminal for good filter characteristics.

The right figure will be the example of the impedance-matching between the CF and Pin2 using an external resistor R1. In this case, the external capacitor C1 is placed.

Without C1 case, the external resistor R1 will be connected to Pin2 directly, so the inner bias voltage fluctuates and the demodulated sensitivity will be degrading.

The external resistor R1 can be calculated by the following equation.

$$\frac{1}{R1} = \frac{1}{Z} - \frac{1}{10k\Omega}$$



%Since the standard evaluation board doesn't have CF, so R1 is 51 Ω to match the impedance of Signal Generator.

· IF IN terminal (Pin2), IF decoupling terminal (Pin3): external capacitor and frequency characteristics

A minimum cutoff frequency of an IF amplifier frequency response will be related with the capacitor connected to IF IN terminal and IF DEC terminal (The upper limit cutoff frequency doesn't change).

Big capacitor value even can amplify a low frequency, and small capacitor value amplifies only the 10.7MHz neighborhood.

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FM demodulator circuit

This FM demodulator circuit works at low voltage, and could achieve low noise by original circuit technology. A 90 degree phase-shifter and a local signal were necessary as the external parts in the past FM IF demodulator IC, but NJW2311 contributes to equipped area reduction to a set because NJW2311 doesn't require such external parts and other special parts.

FIL1 terminal (Pin4): A noise is removed by external capacitor connected to GND

FIL1 terminal is the connection terminal to an external decoupling capacitor of the reference voltage.

A reference voltage of 1/2 * V * is supplied inside the IC, and terminal impedance is 25k $\Omega.$

FIL1 terminal connects an external capacitor passed through to GND for the purpose of a noise removal of the internal reference voltage of the IC.

Lower cut-off frequency for removal noise can calculate from the following equation, which is determined from both of $25k\Omega$ of terminal impedance and the external capacitor C3.





• FIL2 terminal (Pin7): Carrier frequency is removed by external capacitor connected to GND

FIL2 terminal is the noise removal terminal of the demodulated signal.

FIL2 terminal connects an external capacitor connected to GND for the purpose of carrier frequency removal from an FM demodulated output signal. If the carrier frequency is so different from the standard carrier frequency (10.7MHz), there is a possibility that an FM demodulated output has much a carrier frequency leak. When there are a lot of leaks of a carrier frequency in a FM demodulated output signal, it's effective to reduce the leaks by changing external capacitor C4.



And on the other hand, the external capacitor C4 influences to the response speed (raising-time) when the power becomes supplied, so a big value of the capacitor will make slow response and a small one will be in reverse.



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FM

DEMOD

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CS terminal (Pin8): Usually grounded

CS terminal is an electric current output terminal from an IC inner circuit.

It's usually connected to a GND terminal.

In the increasing of ground impedance case, it increases a noise of the output of the FM demodulator, and S/N will be degraded. Also, the operating electric current decreases.

FIL3 terminal (Pin10): Lower cut-off frequency of the FM demodulated output is determined by the external capacitor connected to V⁺

FIL3 terminal is related to decision about a lower cut-off frequency of the FM demodulated output frequency band as a demodulator filter terminal.

A DC bias of 1/2 * V⁺ is supplied inside the IC, and terminal impedance is $25k\Omega$.

The lower cut-off frequency of the FM demodulated output frequency band is determined by $25k\Omega$ of terminal impedance and external capacitor C5, as calculated from the following formula.





DEM OUT terminal (Pin11): Higher cut-off frequency of the FM demodulated output is determined by the external capacitor connected to GND

DEM OUT terminal is the FM demodulated output.

The terminal impedance is $1k\Omega$.

The higher cut-off frequency of the FM demodulated output frequency band is determined by $1k\Omega$ of terminal impedance and external capacitor C6, as calculated from the following formula.





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Op-amplifier circuit

The Op-amplifier circuit amplifies the signal of the FM demodulated output on DEM OUT terminal (about 51 mVrms under standard condition), and outputs.

The gain of the amplifier can be established by the external resistors.

OP⁺ IN terminal (Pin12): Lower cut-off frequency of the carrier frequency is determined by the external capacitor connected to DEM OUT terminal

 $\mathsf{OP}^+\mathsf{IN}$ terminal is a non-reversed input terminal of the OP-amplifier.

DEMOD OUT terminal is connected to OP⁺ IN terminal through the coupling capacitor C7.

A DC bias of $1/2 * V^{+}$ is supplied inside the IC, and terminal impedance is $25k\Omega$.

The lower cut-off frequency of the Op-amplifier is determined by $25k\Omega$ of terminal impedance and the external capacitor C7, as calculated from the following formula. Demodulated Signal Level vs.



OP IN terminal (Pin13): lower cut-off frequency of the Op-amplifier is determined from C and R

OP⁻ IN terminal is a reversed input terminal of the Op-amplifier. The lower cut-off frequency of a FM demodulated output frequency band is determined from a time constant of the external resistor R2 and the external capacitor C8.

The upper limited frequency of a FM demodulated output is decided from the following formula.

$$fc = \frac{1}{2 * \pi * R2 * C8}$$



OP OUT terminal (Pin14): The gain is determined by the external resistor connected to OP IN terminal

OP OUT terminal is the output terminal of the Op-amplifier. Gain (Av) can be set by applying negative feedback.

The gain is determined from the following formula.

$$Av = 1 + \frac{R3}{R2}$$

> TERMINAL FUNCTION

 $(Ta = 25 \text{ °C}, V^{+}1 = V^{+}2 = 5V, IF IN = 10.7MHz / 100dBuV, fdev = \pm 75kHz, fmod = 1kHz, unless otherwise noted)$

Pin No.	SYMBOL	EQUIVALENT CIRCUIT	VOLTAGE	FUNCTION
1 9	GND1 V⁺1		0 V 5 V	1pin: Main ground terminal 9pin: Main power supply terminal
2 3	IF IN IF DEC		2.6 V	2pin: IF Amplifier Input terminal 3pin: IF Amplifier Decoupling terminal
4	FIL1	9 4 5p 50k 4 5p 50k 4 50k 4 50k 4 50k 4 50k 50k 4 50k 4 50k 50k 50k 50k 50k 50k 50k 50k	2.5 V	Reference voltage decoupling terminal.
5	GND2 V⁺2		0 V 5 V	5pin: IF Amplifier final stage (comparator) ground terminal 6pin: IF Amplifier final stage (comparator) power supply terminal
7	FIL2		2.5 V	Noise removal terminal of the demodulated signal.

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Pin No.	SYMBOL	EQUIVALENT CIRCUIT	VOLTAGE	FUNCTION
8	CS		0 V	Electric current output terminal. Usually connected to GND.
10	FIL3		2.3 V	Demodulator filter terminal.
11	DEM OUT		4 V	Demodulated output terminal.
12 13	OP⁺IN OP⁻IN	9 (1) (1) (1) (1) (1) (1) (1) (1)	2.5 V 2.5 V	Pin 12 : non-inverting input terminal of internal Op-amplifier. Pin 13 :inverting input terminal of internal Op-amplifier.
14	OP OUT	9 320uA 14 500 1	2.5 V	Output terminal of the Op-amplifier.

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NJW2311

SSOP14 Unit: mm

■PACKAGE DIMENSIONS





■ EXAMPLE OF SOLDER PADS DIMENSIONS



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NJW2311

SSOP14

Unit: mm

PACKING SPEC

TAPING DIMENSIONS



SYMBOL	DIMENSION	REMARKS
A	6.95	BOTTOM DIMENSION
В	5.4	BOTTOM DIMENSION
DO	1.55±0.05	
D1	1.55±0.1	
E	1.75±0.1	
F	5.5±0.05	
P0	4.0±0.1	
P1	8.0±0.1	
P2	2.0±0.05	
T	0.3±0.05	
T2	2.2	
Ŵ	12.0±0.3	
W1	95	THICKNESS 0. 1max

REEL DIMENSIONS



SYMBOL	DIMENSION
Α	φ254±2
В	φ100±1
С	φ 13±0.2
D	φ 21±0.8
E	2±0.5
W	13.5±0.5
W1	2±0.2

TAPING STATE



PACKING STATE



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EAE-D1006-000-02

■RECOMMENDED MOUNTING METHOD

INFRARED REFLOW SOLDERING METHOD



of mold package.

d

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۰C

120°C

80°C

а

b

Room Temp



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